

SERCOS, an acronym for **SE**rial **R**ealtime **CO**mmunications

Systems, is a standard digital

industrial CNC applications.

SERCOS is a European (EN

standard (IEC 61491). The

optical interface allows data

rates of 2,4,8 and 16 MBd and

controls and drives via fiber-

isolation and noise immunity.

The HFBR-1506AM and HFBR-

guaranteed performance up to

optic rings, with voltage

2506AM products have a

data transfer between numerical

61491) and international

interface for communication in

Agilent HFBR-1506AM/HFBR-2506AM Fiber Optic SMA Transmitters and Receivers for 16 MBd SERCOS Applications

Data Sheet



Handling and Design Information

When soldering, it is advisable to leave the protective cap on the unit to keep the optics clean. Good system performance requires clean port optics and cable ferrules to avoid obstructing the optical path. Clean compressed air often is sufficient to remove particles of dirt; methanol on a cotton swab also works well.

Recommended Chemicals for Cleaning/Degreasing

Alcohols: methyl, isopropyl, isobutyl.

Aliphatics: hexane, heptane.

Other: soap solution, naphtha.

Do not use partially halogenated hydrocarbons such as 1,1,1 trichloroethane, ketones such as MEK, acetone, chloroform, ethyl acetate, methylene dichloride, phenol, methylene chloride or Nmethylpyrolldone. Also, Agilent does not recommend the use of cleaners that use halogenated hydrocarbons because of their potential environmental harm.

Features

- Meets Industrial SERCOS 16MBd standard
- SMA ports
- 650 nm wavelength
- Metal coated, plastic packaging
- Specified for use with 1 mm POF and 200 µm HCS
- DC 16 MBd data rate

Applications

- Industrial Control Data Links
- Factory Automation Data Links
- Voltage Isolation Applications

Package Information

16 MBd.

Description

The transmitters and receivers are housed in a low-cost, dualin-line package that is made of high strength, heat resistant, chemically resistant and UL 94V-O (UL file # E121562) flame retardant plastic. Both the transmitter and receiver are coated with a layer of conductive alloy for better air discharge (ESD) performance. The package is designed for auto insertion and wave soldering so it is ideal for high volume production applications.



CAUTION: The small junction size inherent in the design of these components increases the components' susceptibility to damage from electrostatic discharge (ESD). It is advised that normal static precautions be taken in handling and assembly of these components to prevent damage and/or degradation which may be induced by ESD.

Table 1. Link Performance Specification

0 °C to +70 °C unless otherwise noted.

Parameter	Symbol	Min	Max	Unit	Condition	Reference
Link distance with	1	0.1	45	m	POF	Note 1, 2, 4, 6
HFBR-1506AM/2506AM		0.1	200	m	HCS	Note 1, 3, 5, 6

Notes:

1. 60 mA nominal drive current.

2. POF HFBR-Exxyyy 0.23 dB/m worst case attenuation.

3. HCS 10 dB/km worst case attenuation.

4. Including a 3 dB optical safety margin accounting for link service lifetime.

5. Including a 2 dB optical safety margin accounting for link service lifetime.

6. Signaling rate dc to 16 MBd.

HFBR-1506AM Transmitter The HFBR-1506AM transmitter incoporates a 650nm LED in a metal-coated, plastic housing. The high light output power enables the use of both plastic optical fiber (POF) and Hard Clad Silica (HCS). This	Н	BOTTOM VIEW, HFBR-1506AM SEE NOTE 4	
transmitter can operate up to	PIN	FUNCTION	
16MBd using a simple driver	1	CONNECTED TO PIN 4	
circuit. The HFBR-1506AM is	4	CONNECTED TO PIN 1 GND	
compatible with SMA	6	GND	
connectors.	7	CATHODE	
connectors.	8	ANODE	

Absolute Maximum Ratings

Figure 1.

Parameter	Symbol	Min	Max	Unit	Notes
Storage and Operating Temperature	T _s , o	-40	+85	°C	
Peak Forward Input Current	I _F , _{PK}		90	mA	1
Average Forward Input Current	F, AVG		60	mA	
Reverse Input Voltage	V _R		3	V	
Lead Soldering Cycle					
Temp	T _{SOL}		260	С	2
Time	T _{SOL}		10	S	

Notes:

1. For I F_PK > 60 mA, the duty factor must maintain I F_AVG <= 60 mA and pulse width <= 1 μ s.

2. 1.6 mm below seating plane.

Electrical Characteristics Table

0 °C to +70 °C unless otherwise noted.

Parameter	Symbol	Min	Typ ¹	Max	Unit	Condition	Notes
Optical Power Temperature Coefficient	$\Delta P_T / \Delta T$		-0.02		dB/°C		
Forward Voltage	V _F	1.8	2.1	2.65	V	$I_{F, dc} = 60 \text{ mA}$	See Figure 2
Forward Voltage Temperature Coefficient	$\Delta V_F / \Delta T$		-1.8		mV/°C		See Figure 2
Breakdown Voltage	V_{BR}	3.0	13		V	$I_{\text{Fr dc}}$ = -10 μA	
Peak Emission Wavelength	$\lambda_{ extsf{pk}}$	640	650	660	nm		See Figure 4
Full Width Half Max	FWHM		21	30	nm		See Figure 4
Diode Capacitance	Co		60		pF	$V_F = 0$ V, f = 1 MHz	
Thermal Resistance	$ heta_{ extsf{JC}}$		140		°C/W		Notes 2, 3
Rise Time (10% to 90%)	t _r			15	ns	10% to 90%	See Figure 6
Fall Time (90% to 10%)	t _f			15	ns	— I _F = 60 mA	See Figure 6

Notes:

1. Typical data are at +25 °C

2. Thermal resistance is measured with the transmitter coupled to a connector assembly and fiber, and mounted on a printed circuit board.

3. To further reduce the thermal resistance, the cathode trace should be made as large as is consistent with good RF circuit design.

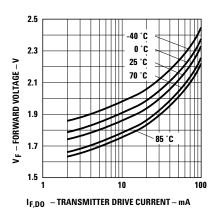
4. Pins 1 and 4 are for mounting and retaining purposes, but are electrically connected, pins 5 and 6 are electrically isolated. It is recommended that pins 1, 4, 5 and 6 all be connected to ground to reduce coupling of elecrical noise.

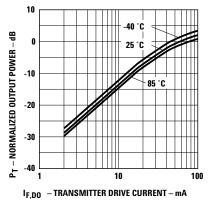
Peak Output Power

0 °C to +70 °C unless otherwise noted.								
Model Number	Symbol	Min	Max	Unit	Condition	Reference		
HFBR-1506AM	Pr	-6.0 -18.0	-2.0 -10.0	dBm	POF, $I_{F, dc} = 60 \text{ mA}$ HCS [®] , $I_{F, dc} = 60 \text{ mA}$	Note 1 Figure 3		

Notes:

1. Optical power measured at the end of 1 meters of 1 mm diameter plastic or 200 μ m hard/plastic clad silica optical fiber with a large area detector.





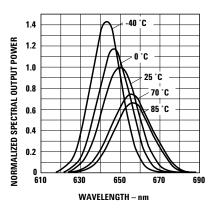


Figure 2. Typical Forward Voltage vs Drive Current

Figure 3. Typical Normalized Optical Power vs Drive Current

Figure 4. Typical Normalized Optical Spectra

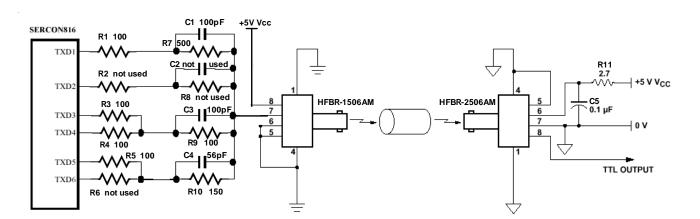
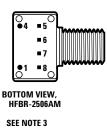


Figure 5. Recommended drive circuit according to SERCOS An17 (I $_{\rm fnom} \sim 35$ mA)

HFBR-2506AM Receiver

The HFBR-2506AM receiver is housed in a metal-coated, plastic package, consists of a silicon PIN photodiode and digitizing IC to produce a logic compatible output. The IC includes a unique circuit to correct the pulse width distortion of the first bit after a long idle period. This enables operation from DC to 16MBd with low PWD for arbitrary data patterns. The receiver is a "push-pull" stage compatible with TTL and CMOS logic. The HFBR-2506AM is compatible with SMA connectors.



PIN	FUNCTION
1	CONNECTED TO PIN 4
4	CONNECTED TO PIN 1
5	NO CONNECT
6	VCC
7	GND
8	vo

Figure 6.

Absolute Maximum Ratings

Parameter	Symbol	Min	Max	Unit	Notes
Storage and Operating Temperature	T _s , ₀	-40	+85	٥°	
Supply Voltage	V _{cc}	-0.5	5.5	V	
Average Output Current	I ₀ , _{AVG}		16	mA	
Output Power Dissipation	P _{od}		80	mW	
Lead Soldering Cycle Temp Time	T _{sol} T _{sol}		260 10	°C s	1

Notes:

1. 1.6 mm below seating plane.

Electrical Characteristics Table

0 °C to +70 °C, 4.75 V < V_{CC} < 5.25 V, V_{P-P} Noise < = 100 mV unless otherwise noted.

Parameter	Symbol	Min	Typ ¹	Max	Unit	Condition	Notes
Peak Input Power Level Logic HIGH	P _{RH}			-42 -44	dBm	1 mm POF 200 µm HCS	
Peak Input Power Level Logic LOW	P _{RL}	-20 -22		-2 -10	dBm	1 mm POF 200 µm HCS PWD < 19 ns	2
Supply Current	Icc		27	45	mA	$V_0 = 0$ pen	
High Level Output Voltage	V _{OH}	4.2	4.7		V	$I_0 = 40 \ \mu A$	
Low Level Output Voltage	V _{OH}		0.22	0.4	V	$I_0 = 1.6 \text{ mA}$	
Pulse Width Distortion	PWD	-19		19	ns		
Propagation Delay Time	T _{P_HL} or			150	ns		

Notes:

1. Typical data are at +25 °C, V_{CC} = 5.0 V

2. BER <= 10E-9, includes a 10.8 dB margin below the receiver switching threshold level (signal to noise ratio =12)

3. Pins 1 and 4 are for mounting and retaining purposes, but are electrically connected, pins 5 and 6 are electrically isolated. It is recommended that pins 1, 4, 5 and 6 all be connected to ground to reduce coupling of electrical noise

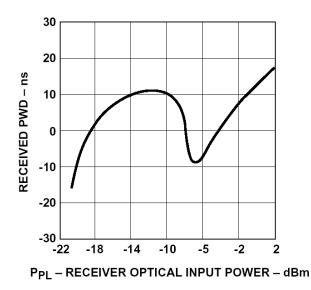


Figure 7. Typical POF receiver pulse width distortion vs optical power

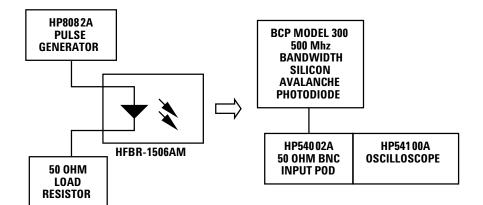
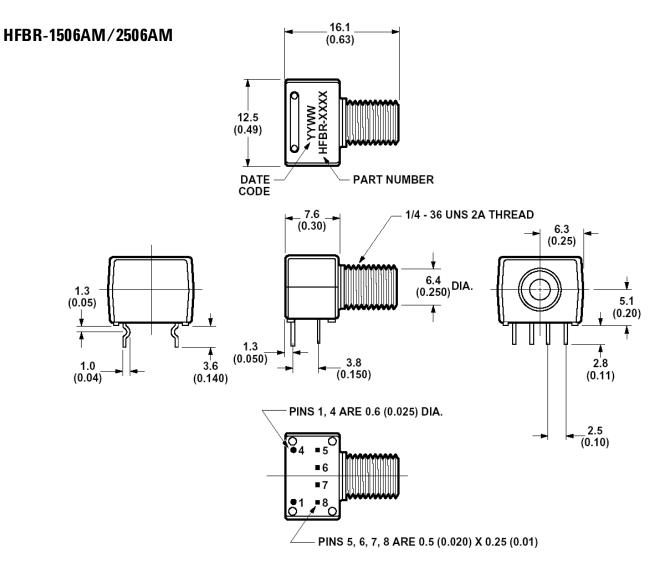


Figure 8. Test Circuit for Measuring Unpeaked Rise and Fall Times

Mechanical Dimensions



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